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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	20 ns
/oltage Supply - Internal	4.75V ~ 5.25V
Number of Logic Elements/Blocks	16
lumber of Macrocells	64
Number of Gates	2000
lumber of I/O	32
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	44-LCC (J-Lead)
Supplier Device Package	44-PLCC (16.59x16.59)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/isplsi-1016-60lj

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ispLSI® 1016 Device Datasheet

September 2010

All Devices Discontinued!

Product Change Notifications (PCNs) have been issued to discontinue all devices in this data sheet.

The original datasheet pages have not been modified and do not reflect those changes. Please refer to the table below for reference PCN and current product status.

Product Line	Ordering Part Number	Product Status	Reference PCN
	ispLSI 1016-60LJ		
	ispLSI 1016-80LJ		
	ispLSI 1016-90LJ		
	ispLSI 1016-110LJ		
	ispLSI 1016-60LJI		PCN#13-10
ispLSI 1016	ispLSI 1016-60LT44	Discontinued	
	ispLSI 1016-80LT44		
	ispLSI 1016-90LT44		
	ispLSI 1016-60LT44I		
	ispLSI 1016-60LH/883		PCN#05A-10
	5962-9476201MXC		F GIN#03A-10



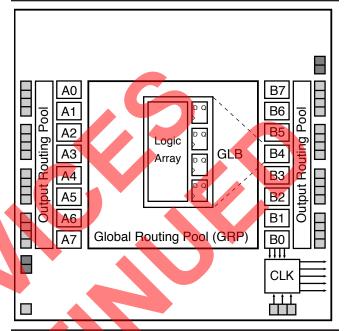
ispLSI® 1016

In-System Programmable High Density PLD

Features

- HIGH-DENSITY PROGRAMMABLE LOGIC
 - High-Speed Global Interconnect
 - 2000 PLD Gates
 - 32 I/O Pins, Four Dedicated Inputs
 - 96 Registers
 - Wide Input Gating for Fast Counters, State Machines, Address Decoders, etc.
 - Small Logic Block Size for Random Logic
 - Security Cell Prevents Unauthorized Copying
- HIGH PERFORMANCE E²CMOS® TECHNOLOGY
- fmax = 110 MHz Maximum Operating Frequency
- fmax = 60 MHz for Industrial and Military/883 Devices
- tpd = 10 ns Propagation Delay
- TTL Compatible Inputs and Outputs
- Electrically Erasable and Reprogrammable
- Non-Volatile E²CMOS Technology
- 100% Tested
- IN-SYSTEM PROGRAMMABLE
 - In-System Programmable™ (ISP™) 5-Volt Only
 - Increased Manufacturing Yields, Reduced Time-to-Market, and Improved Product Quality
 - Reprogram Soldered Devices for Faster Debugging
- COMBINES EASE OF USE AND THE FAST SYSTEM SPEED OF PLDs WITH THE DENSITY AND FLEX-IBILITY OF FIELD PROGRAMMABLE GATE ARRAYS
 - Complete Programmable Device Can Combine Glue Logic and Structured Designs
 - Three Dedicated Clock Input Pins
 - Synchronous and Asynchronous Clocks
 - Flexible Pin Placement
 - Optimized Global Routing Pool Provides Global Interconnectivity

Functional Block Diagram



Description

The ispLSI 1016 is a High-Density Programmable Logic Device containing 96 Registers, 32 Universal I/O pins, four Dedicated Input pins, three Dedicated Clock Input pins and a Global Routing Pool (GRP). The GRP provides complete interconnectivity between all of these elements. The ispLSI 1016 features 5-Volt in-system programming and in-system diagnostic capabilities. It is the first device which offers non-volatile reprogrammability of the logic, as well as the interconnect to provide truly reconfigurable systems.

The basic unit of logic on the ispLSI 1016 device is the Generic Logic Block (GLB). The GLBs are labeled A0, A1 .. B7 (see figure 1). There are a total of 16 GLBs in the ispLSI 1016 device. Each GLB has 18 inputs, a programmable AND/OR/XOR array, and four outputs which can be configured to be either combinatorial or registered. Inputs to the GLB come from the GRP and dedicated inputs. All of the GLB outputs are brought back into the GRP so that they can be connected to the inputs of any other GLB on the device.

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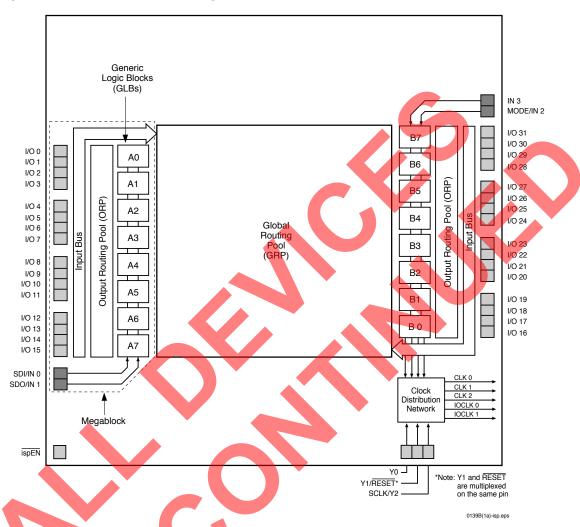
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1016 10



Functional Block Diagram

Figure 1. ispLSI 1016 Functional Block Diagram



The device also has 32 I/O cells, each of which is directly connected to an I/O pin. Each I/O cell can be individually programmed to be a combinatorial input, registered input, latched input, output or bi-directional I/O pin with 3-state control. Additionally, all outputs are polarity selectable, active high or active low. The signal levels are TTL compatible voltages and the output drivers can source 4 mA or sink 8 mA.

Eight GLBs, 16 I/O cells, two dedicated inputs and one ORP are connected together to make a Megablock (see figure 1). The outputs of the eight GLBs are connected to a set of 16 universal I/O cells by the ORP. The ispLSI 1016 device contains two of these Megablocks.

The GRP has as its inputs the outputs from all of the GLBs and all of the inputs from the bi-directional I/O cells. All of these signals are made available to the inputs of the GLBs. Delays through the GRP have been equalized to minimize timing skew.

Clocks in the ispLSI 1016 device are selected using the Clock Distribution Network. Three dedicated clock pins (Y0, Y1 and Y2) are brought into the distribution network, and five clock outputs (CLK 0, CLK 1, CLK 2, IOCLK 0 and IOCLK 1) are provided to route clocks to the GLBs and I/O cells. The Clock Distribution Network can also be driven from a special clock GLB (B0 on the ispLSI 1016 device). The logic of this GLB allows the user to create an internal clock from a combination of internal signals within the device.



Absolute Maximum Ratings 1

Supply Voltage V_{cc} -0.5 to +7.0V

Input Voltage Applied-2.5 to V_{CC} +1.0V

Off-State Output Voltage Applied -2.5 to V_{CC} +1.0V

Storage Temperature-65 to 150°C

Case Temp. with Power Applied-55 to 125°C

Max. Junction Temp. (T_J) with Power Applied ... 150°C

DC Recommended Operating Conditions

SYMBOL	PARAMETER			MIN.	MAX.	UNITS
		Commercial $T_A = 0^{\circ}$	C to +70°C	4.75	5.25	
V CC	Supply Voltage	Industrial $T_A = -4$	0°C to +85°C	4.5	5.5	V
		Military/883 $T_c = -5$	5°C to +125°C	4.5	5.5	
VIL	Input Low Voltage			0	0.8	V
V IH	Input High Voltage			2.0	V cc + 1	V

Table 2- 0005Aisp w/mil.eps

Capacitance ($T_A=25^{\circ}C$, f=1.0 MHz)

SYMBOL	PARAMETER		MAXIMUM	UNITS	TEST CONDITIONS
C ₁	Dedicated Input Capacitance	Commercial/Industrial	8	pf	V _{CC} =5.0V, V _{IN} =2.0V
\	Bedicated input Capacitance	Military	10	pf	V _{CC} =5.0V, V _{IN} =2.0V
C ₂	I/O and Clock Capacitance		10	pf	$V_{CC} = 5.0 \text{V}, V_{I/O}, V_{Y} = 2.0 \text{V}$

^{1.} Guaranteed but not 100% tested.

Table 2- 0006

Data Retention Specifications

PARAMETER		MINIMUM	MAXIMUM	UNITS
Data Retention		20	_	Years
Erase/Reprogram Cycles		10000	_	Cycles

Table 2- 0008B

^{1.} Stresses above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or at any other conditions above those indicated in the operational sections of this specification is not implied (while programming, follow the programming specifications).

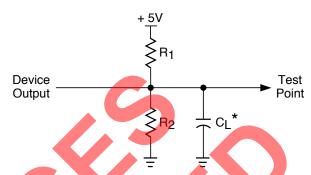


Switching Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise and Fall Time	≤ 3ns 10% to 90%
Input Timing Reference Levels	1.5V
Output Timing Reference Levels	1.5V
Output Load	See figure 2

3-state levels are measured 0.5V from steady-state active level. Table 2- 0003

Figure 2. Test Load



CL includes Test Fixture and Probe Capacitance.

Output Load Conditions (see figure 2)

Tes	Test Condition		R2	CL
Α		470Ω	390Ω	35pF
В	Active High	∞	390Ω	35pF
	Active Low	470Ω	390Ω	35pF
С	Active High to Z at V _{OH} - 0.5V	∞	390Ω	5pF
	Active Low to Z	470Ω	390Ω	5pF
	at V _{OL} + 0.5V			

Table 2- 0004A

DC Electrical Characteristics

Over Recommended Operating Conditions

SYMBOL	PARAMETER	CONDIT	ION	MIN.	TYP. 3	MAX.	UNITS
V OL	Output Low Voltage	I _{OL} =8 mA		-	_	0.4	V
V OH	Output High Voltage	I _{OH} =-4 mA		2.4	_	-	V
I⊫	Input or I/O Low Leakage Current	$0V \le V_{IN} \le V_{IL} (MAX.)$		_	_	-10	μΑ
Iн	Input or I/O High Leakage Current	$3.5V \le V_{IN} \le V_{CC}$		_	_	10	μΑ
IL-isp	isp Input Low Leakage Current	$0V \le V_{IN} \le V_{IL} (MAX.)$		_	_	-150	μΑ
IIL-PU	I/O Active Pull-Up Current	$0V \le V_{IN} \le V_{IL}$		_	_	-150	μΑ
los1	Output Short Circuit Current	$V_{CC} = 5V, V_{OUT} = 0.5V$		_	_	-200	mA
ICC ^{2,4}	Operating Power Supply Current	$V_{IL} = 0.5V, V_{IH} = 3.0V$	Commercial	_	100	150	mA
		f _{TOGGLE} = 1 MHz	Industrial/Military	_	100	170	mA

- 1. One output at a time for a maximum duration of one second. $V_{out} = 0.5V$ was selected to avoid test problems by tester ground degradation. Characterized but not 100% tested.
- 2. Measured using four 16-bit counters.
- Typical values are at V_{CC} = 5V and T_A = 25°C.
 Maximum I_{CC} varies widely with specific device configuration and operating frequency. Refer to the Power Consumption section of this datasheet and Thermal Management section of the Lattice Semiconductor Data Book or CD-ROM to estimate maximum I_{cc} . Table 2-0007A-16 w/mil

External Timing Parameters

Over Recommended Operating Conditions

PARAMETER	TEST 5	# 2	DESCRIPTION ¹		10	-6	00	UNITS
Anameren	COND.	"	Second How	MIN.	MAX.	MIN.	MAX.	
t pd1	Α	1	Data Propagation Delay, 4PT bypass, ORP bypass	_	10	_	12	ns
t pd2	Α	2	Data Propagation Delay, Worst Case Path	_	14.5	_	17	ns
f max (Int.)	Α	3	Clock Frequency with Internal Feedback ³	111	_	90.9	_	MHz
fmax (Ext.)	_	4	Clock Frequency with External Feedback $(\frac{1}{tsu2 + tco1})$	70.1	_	58.8	_	MHz
f max (Tog.)	_	5	Clock Frequency, Max Toggle ⁴	125	_	125	_	MHz
t su1	_	6	GLB Reg. Setup Time before Clock, 4PT bypass	4.5	_	6	-	ns
t co1	Α	7	GLB Reg. Clock to Output Delay, ORP bypass	_	7	G	8	ns
t h1	_	8	GLB Reg. Hold Time after Clock, 4 PT bypass	0	7	0	7	ns
t su2	_	9	GLB Reg. Setup Time before Clock	7.5	7	9	Y	ns
tco2	_	10	GLB Reg. Clock to Output Delay		8.5		10	ns
t h2	_	11	GLB Reg. Hold Time after Clock	0	7-	0	_	ns
t r1	Α	12	Ext. Reset Pin to Output Delay	_	14	_	15	ns
trw1	_	13	Ext. Reset Pulse Duration	10	_	10	_	ns
t en	В	14	Input to Output Enable	_	15	_	15	ns
t dis	С	15	Input to Output Disable	_	15	_	15	ns
t wh	_	16	Ext. Sync. Clock Pulse Duration, High	4	_	4	_	ns
twl	_	17	Ext. Sync. Clock Pulse Duration, Low	4	_	4	_	ns
t su5	_	18	I/O Reg. Setup Time before Ext. Sync. Clock (Y1, Y2)	2	_	2	_	ns
t h5	_	19	I/O Reg. Hold Time after Ext. Sync. Clock (Y1, Y2)	5.5	_	6.5	_	ns

- Unless noted otherwise, all parameters use a GRP load of 4 GLBs, 20 PTXOR path, ORP and Y0 clock.
 Refer to Timing Model in this data sheet for further details.

- Standard 16-Bit loadable counter using GRP feedback.
 fmax (Toggle) may be less than 1/(twh + twl). This is to allow for a clock duty cycle of other than 50%.
- 5. Reference Switching Test Conditions Section.

Table 2-0030-16/110,90C





External Timing Parameters

Over Recommended Operating Conditions

PARAMETER TEST 5			DESCRIPTION ¹	-8	30	-6	60	UNITS
AIIAMETEII	COND.	π	DESCRIPTION	MIN.	MAX.	MIN.	MAX.	
t pd1	Α	1	Data Propagation Delay, 4PT bypass, ORP bypass	-	15	-	20	ns
t pd2	Α	2	Data Propagation Delay, Worst Case Path	-	20	_	25	ns
f max (Int.)	Α	3	Clock Frequency with Internal Feedback ³	80	_	60	_	MHz
fmax (Ext.)	_	4	Clock Frequency with External Feedback $(\frac{1}{tsu2 + tco1})$	50	_	38	_	MHz
f max (Tog.)	_	5	Clock Frequency, Max Toggle ⁴	100	_	83	_	MHz
t su1	_	6	GLB Reg. Setup Time before Clock, 4PT bypass	7	_	9	1	ns
t co1	Α	7	GLB Reg. Clock to Output Delay, ORP bypass	-	10	K	13	ns
t h1	_	8	GLB Reg. Hold Time after Clock, 4 PT bypass	0		0	7	ns
t su2	_	9	GLB Reg. Setup Time before Clock	10	(-7	13	7	ns
tco2	_	10	GLB Reg. Clock to Output Delay	4	12	7	16	ns
t h2	_	11	GLB Reg. Hold Time after Clock	0	-	0	_	ns
t r1	Α	12	Ext. Reset Pin to Output Delay	-	17	_	22.5	ns
trw1	_	13	Ext. Reset Pulse Duration	10	7-	13	-	ns
t en	В	14	Input to Output Enable	-	18	-	24	ns
t dis	С	15	Input to Output Disable	_	18	-	24	ns
t wh	_	16	Ext. Sync. Clock Pulse Duration, High	5	-	6	_	ns
twl	_	17	Ext. Sync. Clock Pulse Duration, Low	5	_	6	_	ns
t su5	_	18	I/O Reg. Setup Time before Ext. Sync. Clock (Y1, Y2)	2	_	2.5	_	ns
t h5	_	19	I/O Reg. Hold Time after Ext. Sync. Clock (Y1, Y2)	6.5	_	8.5	_	ns

Table 2-0030-16/80,60C

- 1. Unless noted otherwise, all parameters use a GRP load of 4 GLBs, 20 PTXOR path, ORP and Y0 clock.
- 2. Refer to Timing Model in this data sheet for further details.
- 3. Standard 16-Bit loadable counter using GRP feedback.
- 4. fmax (Toggle) may be less than 1/(twh + twl). This is to allow for a clock duty cycle of other than 50%.
- 5. Reference Switching Test Conditions Section.





PARAMETER	# ²	DESCRIPTION	-1	10	-6	90	UNITS
PANAIVIETEN	#	DESCRIPTION			MIN.	MAX.	ONITS
Inputs			_				•
t iobp	20	I/O Register Bypass	_	0.8	_	1.0	ns
t iolat	21	I/O Latch Delay	-	1.7	-	2.0	ns
t iosu	22	I/O Register Setup Time before Clock	4.1	-	4.5	-	ns
t ioh	23	I/O Register Hold Time after Clock	1.8	-	2.0	-	ns
tioco	24	I/O Register Clock to Out Delay	_	1.7	_	2.0	ns
t ior	25	I/O Register Reset to Out Delay	-	2.1	1	2.5	ns
t din	26	Dedicated Input Delay	-	1.7	1	2.0	ns
GRP							
t grp1	27	GRP Delay, 1 GLB Load	-	0.6	-	0.7	ns
t grp4	28	GRP Delay, 4 GLB Loads	-	0.8	_	1.0	ns
t grp8	29	GRP Delay, 8 GLB Loads	-	1.5	_	1.8	ns
t grp12	30	GRP Delay, 12 GLB Loads		2.1	_	2.6	ns
t grp16	31	GRP Delay, 16 GLB Loads	-	2.8	_	3.4	ns
GLB							
t 4ptbp	33	4 Product Term Bypass Path Delay	_	5.3	_	6.5	ns
t 1ptxor	34	1 Product Term/XOR Path Delay	-	6.1	_	7.0	ns
t 20ptxor	35	20 Product Term/XOR Path Delay	_	6.6	_	8.0	ns
t xoradj	36	XOR Adjacent Path Delay ³	-	8.2	_	9.5	ns
t gbp	37	GLB Register Bypass Delay	_	0.5	_	0.5	ns
t gsu	38	GLB Register Setup Time before Clock	0.3	_	1.0	_	ns
t gh	39	GLB Register Hold Time after Clock	2.9	_	3.5	_	ns
t gco	40	GLB Register Clock to Output Delay	-	1.6	-	1.5	ns
t gr	41	GLB Register Reset to Output Delay	-	2.1	-	2.5	ns
t ptre	42	GLB Product Term Reset to Register Delay	_	8.2	_	10.0	ns
t ptoe	43	GLB Product Term Output Enable to I/O Cell Delay	_	9.0	_	9.0	ns
t ptck	44	GLB Product Term Clock Delay	2.8	6.2	3.5	7.5	ns
ORP							
t orp	45	ORP Delay	_	2.0	_	2.5	ns
t orpbp	46	ORP Bypass Delay	-	0.4	_	0.5	ns

^{1.} Internal Timing Parameters are not tested and are for reference only.

^{2.} Refer to Timing Model in this data sheet for further details.

^{3.} The XOR Adjacent path can only be used by Hard Macros.



PARAMETER	# ²	DESCRIPTION	-1	10	-6	90	UNITS
PANAIVIETEN	THANKETER # DESCRIPTION					MAX.	
Outputs							
t ob	47	Output Buffer Delay	_	2.1	_	2.5	ns
t oen	48	I/O Cell OE to Output Enabled	-	3.3	-	4.0	ns
t odis	49	I/O Cell OE to Output Disabled	-	3.3	-	4.0	ns
Clocks							
t gy0	50	Clock Delay, Y0 to Global GLB Clock Line (Ref. clock)	2.9	2.9	3.5	3.5	ns
t gy1/2	51	Clock Delay, Y1 or Y2 to Global GLB Clock Line	2.1	3.8	2.5	4.5	ns
t gcp	52	Clock Delay, Clock GLB to Global GLB Clock Line	0.8	4.2	1.0	5.0	ns
t ioy1/2	53	Clock Delay, Y1 or Y2 to I/O Cell Global Clock Line	2.1	3.8	2.5	4.5	ns
t iocp	54	Clock Delay, Clock GLB to I/O Cell Global Clock Line	0.8	4.2	1.0	5.0	ns
Global Re	set						
t gr	55	Global Reset to GLB and I/O Registers	-	7 .9	_	7.5	ns

^{1.} Internal Timing Parameters are not tested and are for reference only.

^{2.} Refer to Timing Model in this data sheet for further details.



PARAMETER	# ²	DESCRIPTION	-80		-60		UNITS	
PANAIVIETEN	#	DESCRIPTION	MIN.	MAX.	MIN.	MAX.	514113	
Inputs			_			11		
t iobp	20	I/O Register Bypass	_	2.0	_	2.7	ns	
t iolat	21	I/O Latch Delay	-	3.0	_	4.0	ns	
t iosu	22	I/O Register Setup Time before Clock	5.5	-	7.3	-	ns	
t ioh	23	I/O Register Hold Time after Clock	1.0	_	1.3	_	ns	
tioco	24	I/O Register Clock to Out Delay	_	3.0	-	4.0	ns	
tior	25	I/O Register Reset to Out Delay	-	2.5	1	3.3	ns	
t din	26	Dedicated Input Delay	_	4.0		5.3	ns	
GRP								
t grp1	27	GRP Delay, 1 GLB Load	6	1.5	1	2.0	ns	
t grp4	28	GRP Delay, 4 GLB Loads	-	2.0	_	2.7	ns	
t grp8	29	GRP Delay, 8 GLB Loads	-	3.0	_	4.0	ns	
t grp12	30	GRP Delay, 12 GLB Loads		3.8	_	5.0	ns	
t grp16	31	GRP Delay, 16 GLB Loads	-	4.5	_	6.0	ns	
GLB								
t 4ptbp	33	4 Product Term Bypass Path Delay	_	6.5	_	8.6	ns	
t 1ptxor	34	1 Product Term/XOR Path Delay	_	7.0	_	9.3	ns	
t 20ptxor	35	20 Product Term/XOR Path Delay	_	8.0	_	10.6	ns	
t xoradj	36	XOR Adjacent Path Delay ³	-	9.5	_	12.7	ns	
t gbp	37	GLB Register Bypass Delay	_	1.0	_	1.3	ns	
t gsu	38	GLB Register Setup Time before Clock	1.0	-	1.3	_	ns	
t gh	39	GLB Register Hold Time after Clock	4.5	_	6.0	_	ns	
t gco	40	GLB Register Clock to Output Delay	_	2.0	_	2.7	ns	
t gr	41	GLB Register Reset to Output Delay	_	2.5	_	3.3	ns	
t ptre	42	GLB Product Term Reset to Register Delay	_	10.0	_	13.3	ns	
t ptoe	43	GLB Product Term Output Enable to I/O Cell Delay	_	9.0	_	12.0	ns	
t ptck	44	GLB Product Term Clock Delay	3.5	7.5	4.6	9.9	ns	
ORP								
t orp	45	ORP Delay	_	2.5	_	3.3	ns	
t orpbp	46	ORP Bypass Delay	_	0.5	_	0.7	ns	

^{1.} Internal Timing Parameters are not tested and are for reference only.

Refer to Timing Model in this data sheet for further details.
 The XOR Adjacent path can only be used by Hard Macros.

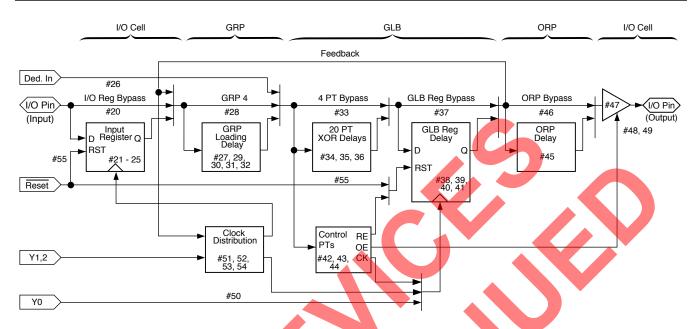


PARAMETER	# ²	DESCRIPTION	-80		-60		UNITS
PANAMETEN	#	DESCRIPTION	MIN.	MAX.	MIN.	MAX.	
Outputs							
t ob	47	Output Buffer Delay	_	3.0	_	4.0	ns
t oen	48	I/O Cell OE to Output Enabled	-	5.0	-	6.7	ns
t odis	49	I/O Cell OE to Output Disabled	-	5.0	-	6.7	ns
Clocks							
t gy0	50	Clock Delay, Y0 to Global GLB Clock Line (Ref. clock)	4.5	4.5	6.0	6.0	ns
t gy1/2	51	Clock Delay, Y1 or Y2 to Global GLB Clock Line	3.5	5.5	4.6	7.3	ns
t gcp	52	Clock Delay, Clock GLB to Global GLB Clock Line	1.0	5.0	1.3	6.6	ns
t ioy1/2	53	Clock Delay, Y1 or Y2 to I/O Cell Global Clock Line	3.5	5,5	4.6	7.3	ns
t iocp	54	Clock Delay, Clock GLB to I/O Cell Global Clock Line	1.0	5.0	1.3	6.6	ns
Global Reset							
t gr	55	Global Reset to GLB and I/O Registers	-	9.0	_	12.0	ns

Internal Timing Parameters are not tested and are for reference only.
 Refer to Timing Model in this data sheet for further details.



ispLSI 1016 Timing Model



Derivations of tsu, th and tco from the Product Term Clock¹

```
tsu = Logic + Reg su - Clock (min)

= (tiobp + tgrp4 + t20ptxor) + (tgsu) - (tiobp + tgrp4 + tptck(min))

= (#20 + #28 + #35) + (#38) - (#20 + #28 + #44)

5.5 ns = (1.0 + 1.0 + 8.0) + (1.0) - (1.0 + 1.0 + 3.5)

th = Clock (max) + Reg h - Logic

= (tiobp + tgrp4 + tptck(max)) + (tgh) - (tiobp + tgrp4 + t20ptxor)

= (#20 + #28 + #44) + (#39) - (#20 + #28 + #35)

3.0 ns = (1.0 + 1.0 + 7.5) + (3.5) - (1.0 + 1.0 + 8.0)

tco = Clock (max) + Reg co + Output

= (tiobp + tgrp4 + tptck(max)) + (tgco) + (torp + tob)

= (#20 + #28 + #44) + (#40) + (#45 + #47)

16.0 ns = (1.0 + 1.0 + 7.5) + (1.5) + (2.5 + 2.5)
```

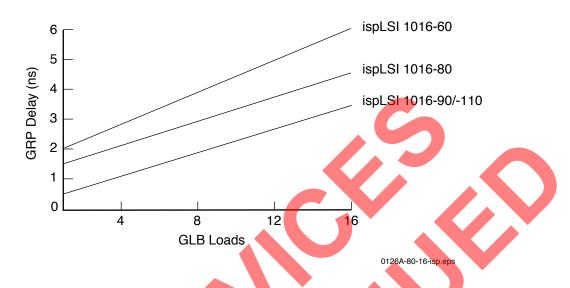
Derivations of tsu, th and tco from the Clock GLB¹

```
\begin{array}{lll} \textbf{tsu} &=& \textbf{Logic} + \textbf{Reg su} + \textbf{Clock (min)} \\ &=& (\textbf{t}iobp + \textbf{t}grp4 + \textbf{t}20ptxor) + (\textbf{t}gsu) - (\textbf{t}gy0(min) + \textbf{t}gco + \textbf{t}gcp(min)) \\ &=& (\#20 + \#28 + \#35) + (\#38) - (\#50 + \#40 + \#52) \\ 5.0 \text{ ns} &=& (1.0 + 1.0 + 8.0) + (1.0) - (3.5 + 1.5 + 1.0) \\ \textbf{th} &=& \textbf{Clock (max)} + \textbf{Reg h} - \textbf{Logic} \\ &=& (\textbf{t}gy0(max) + \textbf{t}gco + \textbf{t}gcp(max)) + (\textbf{t}gh) - (\textbf{t}iobp + \textbf{t}grp4 + \textbf{t}20ptxor) \\ &=& (\#50 + \#40 + \#52) + (\#39) - (\#20 + \#28 + \#35) \\ 3.5 \text{ ns} &=& (3.5 + 1.5 + 5.0) + (3.5) - (1.0 + 1.0 + 8.0) \\ \textbf{tco} &=& \textbf{Clock (max)} + \textbf{Reg co} + \textbf{Output} \\ &=& (\textbf{t}gy0(max) + \textbf{t}gco + \textbf{t}gcp(max)) + (\textbf{t}gco) + (\textbf{t}orp + \textbf{t}ob) \\ &=& (\#50 + \#40 + \#52) + (\#40) + (\#45 + \#47) \\ 16.5 \text{ ns} &=& (3.5 + 1.5 + 5.0) + (1.5) + (2.5 + 2.5) \\ \end{array}
```

1. Calculations are based upon timing specifications for the ispLSI 1016-90.



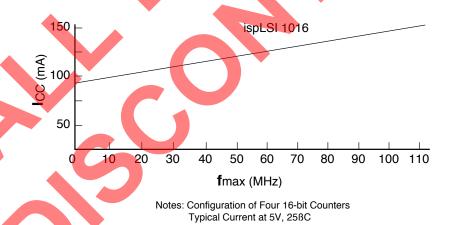
Maximum GRP Delay vs GLB Loads



Power Consumption

Power consumption in the ispLSI 1016 device depends on two primary factors: the speed at which the device is operating, and the number of Product Terms used. Figure 3 shows the relationship between power and operating speed.

Figure 3. Typical Device Power Consumption vs fmax



ICC can be estimated for the ispLSI 1016 using the following equation:

ICC = 31 + (# of PTs * 0.45) + (# of nets * Max. freq * 0.009) where:

of PTs = Number of Product Terms used in design

of nets = Number of Signals used in device

Max. freq = Highest Clock Frequency to the device

The I $_{CC}$ estimate is based on typical conditions (V $_{CC}$ = 5.0V, room temperature) and an assumption of 2 GLB loads on average exists. These values are for estimates only. Since the value of I $_{CC}$ is sensitive to operating conditions and the program in the device, the actual I $_{CC}$ should be verified.



Pin Description

NAME	PLCC PIN NUMBERS	TQFP PIN NUMBERS	JLCC PIN NUMBERS	DESCRIPTION
I/O 0 - I/O 3 I/O 4 - I/O 7 I/O 8 - I/O 11 I/O 12 - I/O 15 I/O 16 - I/O 19 I/O 20 - I/O 23 I/O 24 - I/O 27 I/O 28 - I/O 31	15, 16, 17, 18, 19, 20, 21, 22, 25, 26, 27, 28, 29, 30, 31, 32, 37, 38, 39, 40,	9, 10, 11, 12, 13, 14, 15, 16, 19, 20, 21, 22, 23, 24, 25, 26, 31, 32, 33, 34, 35, 36, 37, 38, 41, 42, 43, 44,	15, 16, 17, 18, 19, 20, 21, 22, 25, 26, 27, 28, 29, 30, 31, 32, 37, 38, 39, 40, 41, 42, 43, 44,	Input/Output Pins - These are the general purpose I/O pins used by the logic array.
IN 3	2	40	2	Dedicated input pins to the device.
ispEN SDI/IN 0 1	13	7	13	Input – Dedicated in-system programming enable input pin. This pin is brought low to enable the programming mode. The MODE, SDI, SDO and SCLK options become active. Input – This pin performs two functions. It is a
SDI/IIV 0	14			dedicated input pin when ispEN is logic high. When ispEN is logic low, it functions as an input pin to load programming data into the device. SDI/IN 0 also is used as one of the two control pins for the isp state machine.
MODE/IN 21	36	30	36	Input – This pin performs two functions. It is a dedicated input pin when ispEN is logic high. When ispEN is logic low, it functions as a pin to control the operation of the isp state machine.
SDO/IN 1 ¹	24	18	24	Input/Output – This pin performs two functions. It is a dedicated input pin when ispEN is logic high. When ispEN is logic low, it functions as an output pin to read serial shift register data.
SCLK/Y2¹	33	27	33	Input — This pin performs two functions. It is a dedicated clock input when ispEN is logic high. This clock input is brought into the Clock Distribution Network, and can optionally be routed to any GLB and/or I/O cell on the device. When ispEN is logic low, it functions as a clock pin for the Serial Shift Register.
Y0	11	5	11	Dedicated Clock input. This clock input is connected to one of the clock inputs of all of the GLBs on the device.
Y1/RESET	35	29	35	This pin performs two functions: Dedicated clock input. This clock input is brought into the Clock Distribution Network, and can optionally be routed to any GLB and/or I/O cell on the device. Active Low (0) Reset pin which resets all of the GLB and I/O registers in the device.
GND VCC	1, 23 12, 34	17, 39 6, 28	1, 23 12, 34	Ground (GND) V _{cc}

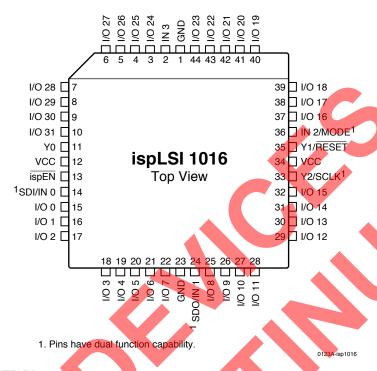
^{1.} Pins have dual function capability.

Table 2 - 0002C-16-isp

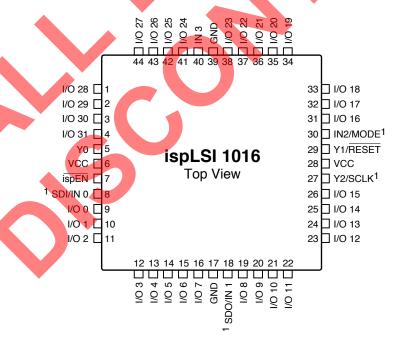


Pin Configuration

ispLSI 1016 44-Pin PLCC Pinout Diagram



ispLSI 1016 44-Pin TQFP Pinout Diagram



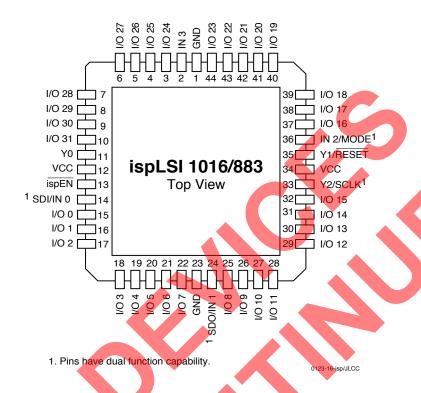
1. Pins have dual function capability.

0851-16/TQFP



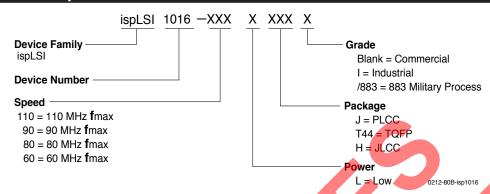
Pin Configuration

ispLSI 1016 44-Pin JLCC Pinout Diagram





Part Number Description



Ordering Information

COMMERCIAL

Family	f max (MHz)	tpd (ns)	Ordering Number	Package
	110	10	ispLSI 1016-110LJ	44-Pin PLCC
	90	12	ispLSI 1016-90LJ	44-Pin PLCC
	90	12	ispLSI 1016-90LT44	44-Pin TQFP
ispLSI	80	15	ispLSI 1016-80LJ	44-Pin PLCC
	80	15	ispLSI 1016-80LT44	44-Pin TQFP
	60	20	ispLSI 1016-60LJ	44-Pin PLCC
	60	20	ispLSI 1016-60LT44	44-Pin TQFP

INDUSTRIAL

Family	f max (MHz)	tpd (ns)	Ordering Number	Package
ispLSI	60	20	ispLSI 1016-60LJI	44-Pin PLCC
ispLSi	60	20	ispLSI 1016-60LT44I	44-Pin TQFP

MILITARY/883

Family	fmax (MHz)	tpd (ns)	Ordering Number	SMD#	Package
ispLSI	60	20	ispLSI 1016-60LH/883	5962-9476201MXC	44-Pin JLCC

Note: Lattice Semiconductor recognizes the trend in military device procurement towards using SMD compliant devices, as such, ordering by this number is recommended.

Table 2-0041-16-isp1016